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UBA2211

Half-bridge power IC family for CFL lamps

Rev. 3 — 26 August 2011

Product data sheet

1. General description

The UBA2211 family of integrated circuits are a range of high voltage monolithic ICs for driving Compact Fluorescent Lamps (CFL) in half-bridge configurations. The family is designed to provide easy integration of lamp loads across a range of burner power and mains voltages.

2. Features and benefits

2.1 System integration

- Integrated half-bridge power transistors
 - ♦ UBA2211A: 220 V mains; 13.5 Ω; 0.9 A maximum ignition current
 - ♦ UBA2211B: 220 V mains; 9 Ω; 1.35 A maximum ignition current
 - ♦ UBA2211C: 220 V mains; 6.6 Ω; 1.85 A maximum ignition current
- Integrated bootstrap diode
- Integrated high voltage supply

2.2 Burner current

- Adjustable current controlled preheat mode enables the preheat time (t_{ph}) to be set
- RMS current control

2.3 Burner lifetime

- Current controlled preheat with adjustable preheat time and preheat current
- Minimum glow time control to support cold start
- Lamp power independent from mains voltage variations
- Lamp inductor saturation protection during ignition

2.4 Safety

- Saturation Current Protection (SCP)
- OverTemperature Protection (OTP)
- Capacitive Mode Protection (CMP)
- Overpower control
- System shutdown when the burner fails to ignite



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2.5 Ease of use

- Adjustable operating frequency for easy fit with various burners
- Each device in the family incorporates the same controller functionality ensuring easy power scaling and roll-out across a complete range of CFLs

3. Applications

■ Compact Fluorescent Lamps up to 25 W for indoor and outdoor applications

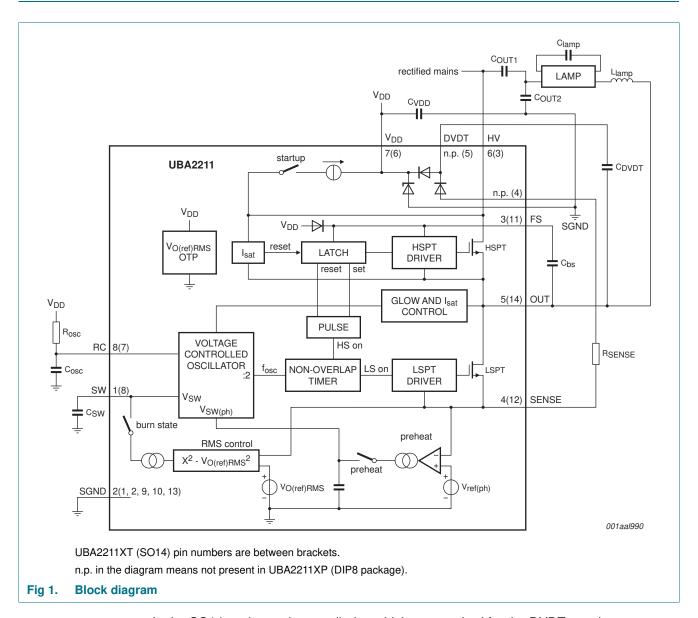
4. Ordering information

Table 1. Ordering information

Type number	Package					
	Name	Description	Version			
UBA2211AP/N1	DIP8	plastic dual in-line package; 8 leads (300 mil)	SOT97-1			
UBA2211BP/N1						
UBA2211CP/N1						
UBA2211AT/N1	SO14	plastic small outline package; 14 leads; body width	SOT108-1			
UBA2211BT/N1		3.9 mm				
UBA2211CT/N1						

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5. Block diagram



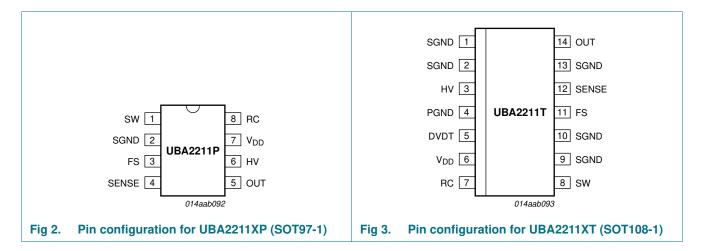
In the SO14 package, the two diodes which are required for the DVDT supply are integrated and connected between pins DVDT and PGND.

Mount these diodes externally when using the DIP8 packaged devices because they are not bonded out.

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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	ymbol Pin I		Description
	UBA2211XP	UBA2211XT	
SW	1	8	sweep timing and VCO input
SGND	2	1, 2, 9, 10, 13	signal ground
FS	3	11	high-side floating supply output
SENSE	4	12	voltage sense for preheat and RMS control
OUT	5	14	half-bridge output
HV	6	3	high-voltage supply
V_{DD}	7	6	internal low-voltage supply output
RC	8	7	internal oscillator input
DVDT	n.p.	5	DVDT supply input
PGND	n.p.	4	DVDT supply ground

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7. Functional description

7.1 Supply voltage

The UBA2211 family is powered using a start-up current source and a DVDT supply. When the voltage on pin HV increases, the V_{DD} capacitor (C_{VDD}) is charged using the internal Junction gate Field-Effect Transistor (JFET) current source. The voltage on pin V_{DD} rises until V_{DD} equals $V_{DD(start)}$. The start-up current source is then disabled. The half-bridge starts switching causing the charge pump to generate the required V_{DD} supply.

The amount of current flowing towards V_{DD} equals $V_{HV} \times C_{DVDT} \times f$ where f represents the momentary frequency. The charge pump consists of an external half-bridge capacitor (C_{DVDT}) . The SO14 package contains two internal diodes with an internal Zener diode. Mount these diodes externally with the DIP8 packaged devices. The Zener diode ensures the V_{DD} voltage cannot rise above the maximum V_{DD} rating.

The DVDT supply has its own ground pin (PGND) to prevent large peak currents from flowing through the external small signal ground pin (SGND).

The start-up current source is enabled when the voltage on pin V_{DD} is below the $V_{DD(stop)}$ level.

7.2 Start-up state

When the supply voltage on pin V_{DD} increases, the IC enters the start-up state. In the start-up state the High-Side Power Transistor (HSPT) is switched off and the Low-Side Power Transistor (LSPT) is switched on. The circuit is reset and the capacitors on the bootstrap pin FS (C_{bs}) and the low-voltage supply pin V_{DD} (C_{VDD}) are charged. Pins RC and SW are switched to ground.

When pin V_{DD} is above $V_{DD(start)}$, the start-up state is exited and the preheat state is entered. If the voltage on pin V_{DD} falls below $V_{DD(stop)}$, the system returns to the start-up state.

Remark: If OTP is active, the IC remains in the start-up state indefinitely. The V_{DD} voltage slowly oscillates between $V_{DD} = V_{DD(stop)}$ and $V_{DD} = V_{DD(start)}$.

7.3 Reset

A DC reset circuit is incorporated in the high-side driver. The high-side transistor is switched off when the voltage on pin FS is below the high-side lockout voltage.

7.4 Oscillation control

The oscillation frequency is based on the 555-timer function. A self oscillating circuit is created comprising the external components: resistors $R_{\rm osc}$, $R_{\rm SENSE}$ and capacitor $C_{\rm osc}$. $R_{\rm osc}$ and $C_{\rm osc}$ determine the nominal oscillating frequency.

An internal divider $0.5 \times f_{osc(int)}$ is used to generate the accurate 50 % duty cycle. The divider sets the bridge frequency at half the oscillator frequency.

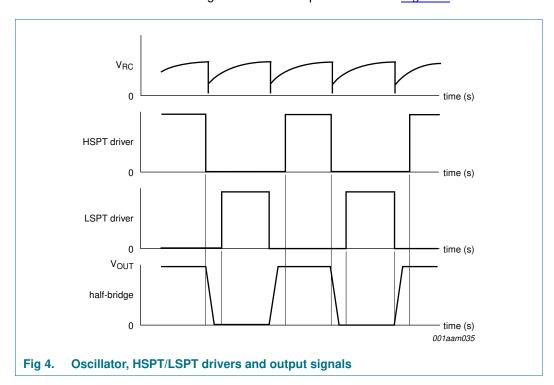
The input on pin SW generates the V_{SW} signal and it is used to determine the frequency in all states except preheat. Signal $V_{SW(ph)}$ is an internally generated signal used to determine the frequency during the preheat state.

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The output voltage of the bridge changes with the falling edge of the signal on pin RC. The nominal half-bridge frequency is shown in Equation 1:

$$f_{osc(nom)} = \frac{1}{k_{osc} \times R_{osc} \times C_{osc}}$$
 (1)

The maximum frequency is $2.5 \times f_{osc(nom)}$ and is set at V_{SW} . An overview of the oscillator, internal LSPT and HSPT drive signals and the output is shown in Figure 4.



7.5 Preheat state

As described in Section 7.2, the IC enters the preheat state when the voltage on pin V_{DD} is above $V_{DD(start)}$ and OTP is not active. The sweep current (I_{SW}) charges the capacitor on pin SW (C_{SW}). The preheat Operational Transconductance Amplifier (OTA) is enabled and the half-bridge circuit starts oscillating.

The preheat current is monitored using the external R_{SENSE} resistor. The OTA controls the frequency using output voltage $V_{SW(ph)}$ so that the peak voltage across R_{SENSE} equals the internal reference voltage $(V_{ref(ph)})$. The peak voltage is the voltage at the end of the LSPT conduction time. The preheat peak current through the lamp filament is calculated as shown in Equation 2:

$$I_{ph(peak)} = \frac{V_{ref(ph)}}{R_{SENSE}} \tag{2}$$

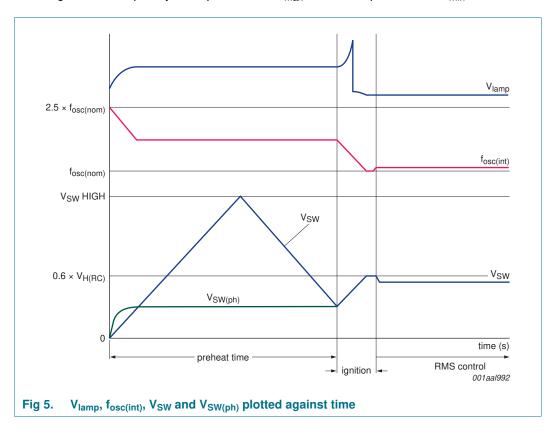
The value of the external capacitor (C_{SW}) sets the preheat time. Typically, the external capacitor is calculated as shown in <u>Equation 3</u>. The preheat state ends when the falling C_{SW} voltage equals $V_{SW(ph)}$; see Figure 4.

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$$C_{sw} = \frac{t_{ph}}{1.5 \text{ s} \times 100 \text{ nF}} \tag{3}$$

If during the preheat time, capacitive mode is sensed and the internal V_{SW} HIGH node is discharged. The frequency sweep restarts at f_{max} which is equal to $2.5 \times f_{min}$.



7.6 Ignition state

The ignition state is entered after the preheat state has finished. The current I_{SW} charges the capacitor on pin SW (C_{SW}) up to $0.6 \times V_{H(RC)}$ which corresponds to the frequency $f_{osc(nom)}$.

During this frequency sweep, the resonance frequency is reached resulting in the ignition of the lamp (see Figure 4). The combination of lamp inductor (L_{lamp}) and lamp capacitor (C_{lamp}) set the resonance frequency. The ignition state ends when the voltage on pin SW (V_{SW}) reaches $0.6 \times V_{H(RC)}$.

7.7 Steady state

In the steady state, the RMS current control is active. This control sets the frequency so that the RMS voltage across the sense resistor (R_{SENSE}) is equal to $V_{O(ref)RMS}$. This ensures the current through the power switches and through the lamp is constant. This results in constant IC dissipation and temperature at a fixed ambient temperature.

During one oscillator clock cycle, the voltage on pin SENSE (V_{SENSE}) is squared and converted into a positive current. This discharge current is added to the capacitor C_{SW} .

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During the other oscillator clock cycle, the input of the squarer is connected to the internal reference voltage $V_{O(ref)RMS}$. This voltage is squared and converted into a negative current. This charge current is also added to capacitor C_{SW} . When both currents are equal, then Equation 4 is true:

$$\frac{1}{T_{osc}} \times \int_{0}^{T_{osc}} V_{SENSE^{2}(t)DT} = \frac{1}{T_{osc}} \times \int_{0}^{T_{osc}} V_{O(ref)RMS^{2}DT}$$
(4)

Where T_{osc} equals the operating frequency $f_{osc} / 1$.

Taking the square root of both sides results in Equation 5:

$$\sqrt{\frac{1}{T_{osc}} \times \int_{0}^{T_{osc}} V_{SENSE^{2}(t)DT}} = \sqrt{\frac{1}{T_{osc}} \times \int_{0}^{T_{osc}} V_{O(ref)RMS^{2}DT}}$$
(5)

or

$$RMS \ V_{SENSE} = V_{O(ref)RMS} = R_{SENSE} \times I_{LSPT}$$
 (6)

A constant current flows through the power switches and the lamp which is defined by the internal reference voltage ($V_{O(ref)RMS}$) and the external R_{SENSE} resistor.

The R_{SENSE} resistor sets both the preheat current and the RMS half-bridge current. The ratio between them is fixed. However by adding a resistor in parallel to C_{sw} (see <u>Figure 7</u>) this ratio can be adjusted. The ratio adjustment is described in more detail in *UM10418*, the *UBA2211 user manual*.

7.8 Non-overlap time

The non-overlap time is defined as the time when both MOSFETs are not conducting. The non-overlap time is fixed internally and is fixed at the t_{no} value (see Table 5).

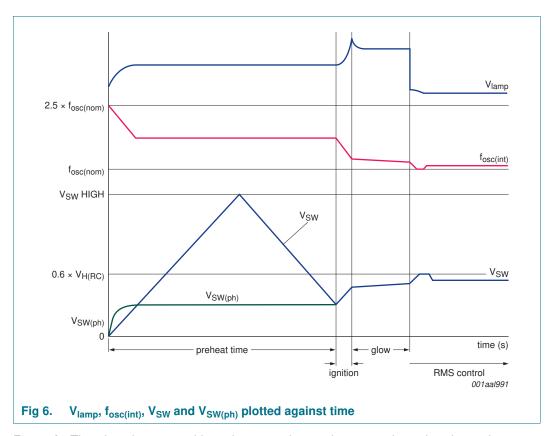
7.9 OverTemperature Protection (OTP)

OTP is active in all states. When the die temperature reaches the OTP activation threshold ($T_{th(act)otp}$), the oscillator is stopped and the power switches (LSPT/HSPT) are set to the start-up state. When the oscillator is stopped, the DVDT supply no longer generates the supply current I_{DVDT} . Voltage V_{DD} gradually decreases and the start-up state is entered as described in Section 7.2 on page 5. OTP is reset when the temperature $< T_{th(rel)otp}$.

7.10 Minimum glow time control

If the preheat time is set too short or omitted, the lamp electrodes do not have the correct temperature in the ignition state. This results in instant light but also in a reduced switching lifetime because when the electrode temperature is too low electrode sputtering and damage occur. The minimum glow time control minimizes electrode damage by ensuring maximum power use during the glow phase to heat the electrodes as quickly as possible (see Figure 6).

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Remark: The glow time control is active as t_{ph} is too short to preheat the electrodes.

7.11 Saturation Current Protection (SCP)

A critical parameter in the design of the lamp inductor is its saturation current. When the momentary inductor exceeds its saturation current, the inductance drops significantly. If the inductance drops significantly, the inductor current and the current flowing through the high-side and low-side power switches increases rapidly. This increase can cause the current to exceed the half-bridge power transistors maximum ratings.

Saturation of the lamp inductor is likely to occur in cost-effective and miniaturized CFLs. The UBA2211 family internally monitors the power transistor current. When this current exceeds the momentary rating of the internal power transistors, the conduction time is reduced and the frequency is slowly increased (by discharging C_{SW}). This action causes the system to balance at the edge of the current rating of the power switches.

7.12 Capacitive Mode Protection (CMP)

When capacitive mode is detected, capacitor C_{SW} is discharged causing the frequency to increase. The system sets itself to the operating point where capacitive mode switching is minimized. CMP is active during the ignition state and in the steady state.

If capacitive mode is sensed during the preheat time, the oscillator restarts at f_{max} (which is $2.5 \times f_{min}$). CMP could be triggered by an end of lamp life condition when a lamp electrode is broken.

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8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	I	Min	Max	Unit
V_{HV}	voltage on pin HV	operating		-	373	V
		mains transients: 10 minutes maximum over lifetime	-	-	550	V
V_{FS}	voltage on pin FS	with respect to pin OUT	(0	14	V
V_{DD}	supply voltage	DC supply	(0	15	V
V_{SENSE}	voltage on pin SENSE		-	-5	+5	V
V _{RC}	voltage on pin RC	I _{RC} < 1 mA	(0	V_{DD}	V
V _{SW}	voltage on pin SW	I _{SW} < 1 mA	(0	V_{DD}	V
l _{OUT}	current on pin OUT	T _j < 125 °C	[1]			
		UBA2211AX	-	-0.9	+0.9	Α
		UBA2211BX	-	-1.35	+1.35	Α
		UBA2211CX	-	-1.65	+1.65	Α
I _{DVDT}	current on pin DVDT	T _j < 125 °C	-	-0.9	+0.9	Α
SR	slew rate	repetitive output on pin OUT	-	-4	+4	V/ns
T _j	junction temperature		-	-40	+150	°C
T _{stg}	storage temperature		-	-55	+150	°C
V _{ESD}	electrostatic discharge	HBM:	[2]			
	voltage	pins HV, FS, OUT		•	1000	V
		pins SW, RC, VDD, DVDT	-	-	2500	٧
		MM:	[3]			
		all pins	-	•	250	V
		CDM:	[3]			
		all pins		-	500	٧

^[1] X where the last letter is P or T.

9. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> 95	K/W
$R_{th(j-c)}$	thermal resistance from junction to case	in free air	<u>[1]</u> 16	K/W

^[1] In accordance with IEC 60747-1

^[2] In accordance with the Human Body Model (HBM): equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

^[3] In accordance with the Machine Model (MM): equivalent to discharging a 200 pF capacitor through a 1.5 k Ω series resistor and a 0.75 μ H inductor.

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10. Characteristics

Table 5. Characteristics

 T_i = 25 °C; all voltages are measured with respect to SGND; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Low-volta	ge supply					
Start-up sta	ate					
I _{HV}	current on pin HV	V _{HV} = 100 V	-	0.85	-	mΑ
V _{DD(start)}	start supply voltage	oscillation start	10.7	11.7	12.7	V
V _{DD(stop)}	stop supply voltage	oscillation stop	8	8.5	9	V
V _{DD(hys)}	hysteresis of supply voltage	start – stop	3	3.5	4	V
V _{DD(reg)}	regulation supply voltage		-	13.8	-	V
I _{sink}	sink current	capability of VDD regulator	6	-	-	mΑ
Output stag	ge					
R _{on}	on-state resistance	high-side transistor:	[1]			
		UBA2211AX; $V_{HV} = 310 \text{ V}$; $I_D = 100 \text{ mA}$	-	13.5	-	Ω
		UBA2211BX; $V_{HV} = 310 \text{ V}$; $I_D = 100 \text{ mA}$	-	9.3	-	Ω
		UBA2211CX; $V_{HV} = 310 \text{ V}$; $I_D = 100 \text{ mA}$	-	6.6	-	Ω
		low-side transistor:	[1]			
		UBA2211AX; $I_D = 100 \text{ mA}$	-	13.5	-	Ω
		UBA2211BX; $I_D = 100 \text{ mA}$	-	8.2	-	Ω
	UBA2211CX; $I_D = 100 \text{ mA}$	-	6.6	-	Ω	
R _{on(150)} / R _{on(25)}	on-state resistance ratio (150 °C to 25 °C)		-	1.4	-	
V _F	forward voltage	HS; I _F = 200 mA	-	-	2	V
		LS; I _F = 200 mA	-	-	2	V
		bootstrap diode; I _F = 1 mA	0.7	1	1.3	V
t _{no}	non-overlap time		1.05	1.35	1.65	μS
V_{FS}	voltage on pin FS	UnderVoltage LockOut with respect to pin OUT	3.6	4.2	4.8	V
I _{FS}	current on pin FS	V _{HV} = 310 V; V _{FS} = 12 V	10	14	18	μΑ
I _{sat}	saturation current	high-side transistor:	[1]			
		UBA2211AX; V_{DS} = 30 V; $T_j \le$ 125 °C; V_{HV} = 310 V	0.90	-	-	Α
		UBA2211BX; V_{DS} = 30 V; $T_j \le$ 125 °C; V_{HV} = 310 V	1.35	-	-	Α
		UBA2211CX; V_{DS} = 30 V; $T_j \le$ 125 °C; V_{HV} = 310 V	1.85	-	-	Α
		low-side transistor:	[1]			
		UBA2211AX; $V_{DS} = 30 \text{ V}$; $T_j \leq 125 \text{ °C}$	0.90	-	-	Α
		UBA2211BX; V _{DS} = 30 V; T _i ≤ 125 °C	1.35	-	-	Α
		UBA2211CX; $V_{DS} = 30 \text{ V}$; $T_j \le 125 \text{ °C}$	1.85	-	-	Α

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 Table 5.
 Characteristics ...continued

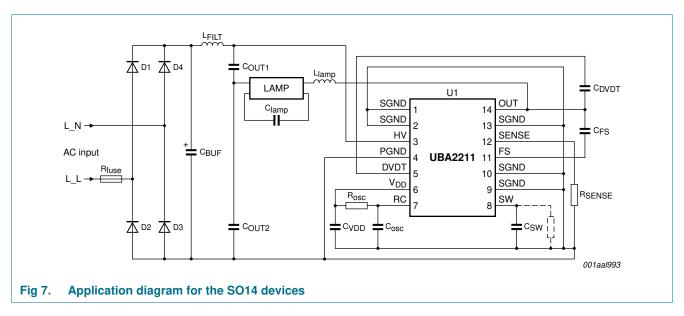
 T_i = 25 °C; all voltages are measured with respect to SGND; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Internal osci	llator					
f _{osc(int)}	internal oscillator frequency	V _{SW} = V _{DD} ; steady state	-	-	60	kHz
f _{osc(nom)}	nominal oscillator frequency	R_{osc} = 100 k Ω ; C_{osc} = 220 pF; V_{SW} = V_{DD}	40.05	41.32	42.68	kHz
f _{osc(max)}	maximum oscillator frequency	R_{osc} = 100 k Ω ; C_{osc} = 220 pF; V_{SW} = 0 V	-	104	-	kHz
$\Delta f_{osc(nom)}/\Delta T$	nominal oscillator frequency variation with temperature	R_{osc} = 100 k Ω ; C_{osc} = 220 pF; ΔT = -20 to +150 °C	-	2	-	%
k _H	high-level trip point factor		0.382	0.395	0.408	
k _L	low-level trip point factor		0.030	0.033	0.036	
$V_{H(RC)}$	HIGH-level voltage on pin RC	trip point; $V_{H(RC)} = k_H \times V_{DD}$	4.58	4.94	5.29	V
$V_{L(RC)}$	LOW-level voltage on pin RC	trip point; $V_{L(RC)} = k_L \times V_{DD}$	0.367	0.413	0.458	V
K _{osc}	oscillator constant	R_{osc} = 100 k Ω ; C_{osc} = 220 pF	1.065	1.1	1.135	
Preheat fund	etion					
$V_{ref(ph)}$	preheat reference voltage		-	620	-	mV
t_{ph}	preheat time	$C_{SW} = 47 \text{ nF}$	-	0.55	-	S
RMS current	control function					
V _{O(ref)RMS}	RMS reference output voltage		262	285	308	mV
OTP function	n					
$T_{th(act)otp}$	overtemperature protection activation threshold temperature		155	175	-	°C
$T_{th(rel)otp}$	overtemperature protection release threshold temperature		-	100	-	°C

^[1] X where the last letter is P or T.

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11. Application information



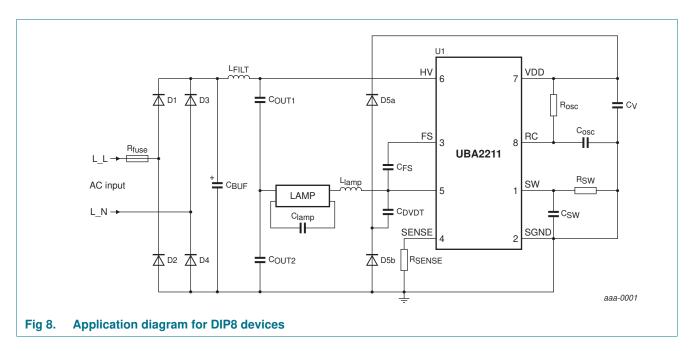
The components used in Figure 7 are illustrated in Table 6.

Table 6. SO14 device bill of materials

Number	Reference	Alias	Typical value	Quantity
1	R _{fuse}		10 Ω; 1 W	1
2	D1, D2, D4, D5		M7	4
3	C _{BUF}	C1	2.7 μF; 400 V; 105 °C; 10*16	1
4	C _{FS}	C5	10 nF; 50 V; 0805	1
5	C_{SW}, C_{VDD}	C6	100 nF; 50 V; 0805	2
6	C _{DVDT}	C9	220 pF; 500 V	1
7	C _{osc}	C7	220 pF; 50 V; 0805	1
9	C0, C _{OUT1} , C _{OUT2}	C0, C2, C3	100 nF; 400 V; CL21	3
10	C_{lamp}	C4	2.2 nF; 1 kV; CBB28	1
11	L _{FILT}	L1	3 mH; LGB	1
12	L_{lamp}	L2	3 mH; EE13; PC40	1
13	R _{osc}	R1	100 kΩ; 1 %; 0805	1
14	R _{SENSE}	R2	1.8 Ω; 1 W; 1 %	1
15	PCB		UBA2211-1; UBA2211-8	2
16	IC		UBA2211B	1
17	Burner		3U-12 W; 2700k	1

Remark: The customized component values depend on the burner characteristics. An on-line tool is available to calculate the required components values. This on-line tool can be found on the product information page of the UBA2211.

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The components used in Figure 8 are illustrated in Table 7.

Table 7. DIP8 device bill of materials

Number	Reference	Alias	Typical value	Quantity
1	R _{fuse}	-	22 Ω; 1 W	1
2	D1, D2, D4, D5	-	M7	4
2	D5a, D5b	-	1N4148	2
3	C _{BUF}	C1	2.7 μF; 400 V; 105 °C; 10*16	1
4	C _{FS}	C5	10 nF; 50 V; 0805	1
5	C_{SW}, C_{VDD}	C6	100 nF; 50 V; 0805	2
6	C_{DVDT}	C9	220 pF; 630 V	1
7	C _{osc}	C7	220 pF; 50 V; 0805	1
9	C _{OUT1,} C _{OUT2}	C0, C2, C3	100 nF; 400 V; CL21	3
10	C_{lamp}	C4	2.2 nF; 1 kV; CBB28	1
11	L _{FILT}	L1	3 mH; LGB	1
12	L_{lamp}	L2	3 mH; EE13; PC40	1
13	R _{osc}	R1	100 kΩ; 1 %; 0805	1
14	R _{SENSE}	R2	1.8 Ω; 1 W; 1 %	1
15	R _{SW}	R _{SW}	not mounted	2
16	IC	-	UBA2211BP	1
17	Burner	-	3U-12 W; 2700k	1

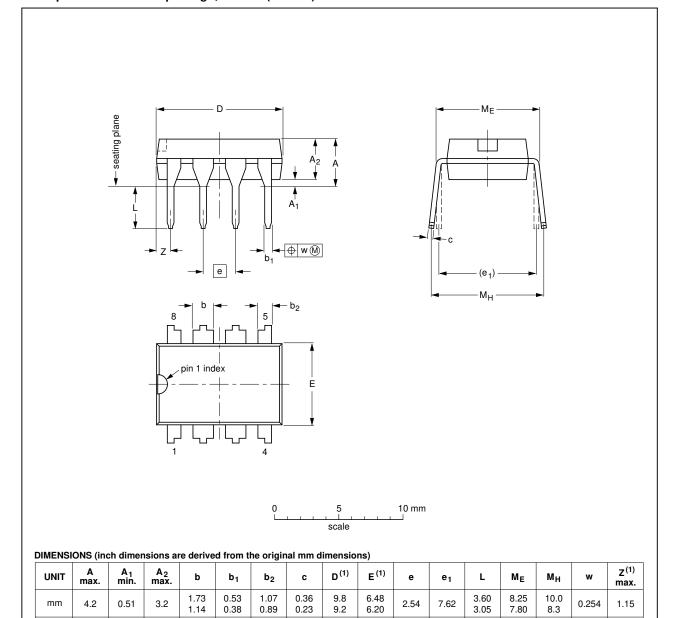
Remark: The customized component values depend on the burner characteristics. An on-line tool is available to calculate the required components values. This on-line tool can be found on the product information page of the UBA2211.

Half-bridge power IC family for CFL lamps

12. Package outline

DIP8: plastic dual in-line package; 8 leads (300 mil)

SOT97-1



Note

inches

0.17

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.021

0.015

0.042

0.035

0.014

0.009

0.068

0.045

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT97-1	050G01	MO-001	SC-504-8			99-12-27 03-02-13

Fig 9. Package outline SOT97-1 (DIP8)

0.02

0.13

UBA2211

0.01

0.045

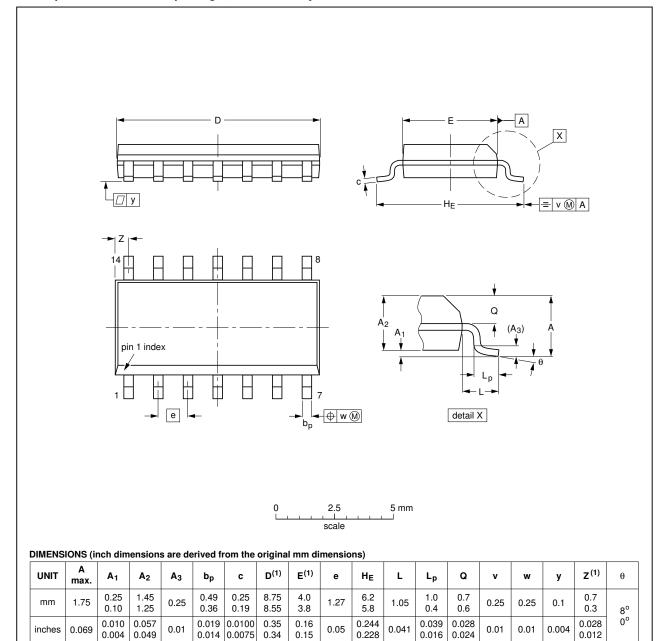
0.32

0.3

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig 10. Package outline SOT108-1 (SO14)

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13. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
UBA2211 v.3	20110826	Product data sheet	-	UBA2211 v.2.1	
Modifications:	 Data sheet status changed from preliminary to product. Figure 8 "Application diagram for DIP8 devices" and Table 7 "DIP8 device bill of materials added. 				
	 Minor text ar 	nd graphics changes.			
UBA2211 v.2.1	20110307	Preliminary data sheet	-	UBA2211 v.2	
UBA2211 v.2	20110103	Objective data sheet	-	UBA2211 v.1	
UBA2211 v.1	20100628	Objective data sheet	-	-	

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14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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